Preferred Device

Small Signal MOSFET 2 Amps, 35, 60, 90 Volts

N-Channel TO-92

MAXIMUM RATINGS

Rating	Symbol	MPF930	MPF960	MPF990	Unit
Drain-Source Voltage	V _{DS}	35	60	90	Vdc
Drain-Gate Voltage	V_{DG}	35	60	90	Vdc
$\label{eq:Gate-Source} Gate-Source \\ Voltage \\ - Continuous \\ - Non-repetitive \\ (t_p \le 50~\mu s)$	V _{GS} V _{GSM}		±20 ±40		Vdc Vpk
Drain Current Continuous (Note 1.) Pulsed (Note 2.)	I _D		2.0		Adc
Total Device Dissipation @ TA = 25°C Derate above 25°C	PD	1.0 8.0		Watts mW/°C	
Operating and Storage Junction Temperature Range	T _J , T _{stg}	-55 to 150			°C
Thermal Resistance	θЈА		125		°C/W

- The Power Dissipation of the package may result in a lower continuous drain current.
- 2. Pulse Test: Pulse Width $\leq 300 \,\mu\text{s}$, Duty Cycle $\leq 2.0\%$.



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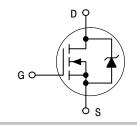
2 AMPERES 35, 60, 90 VOLTS

RDS(on) = 0.7Ω (MPF930)

RDS(on) = 0.8Ω (MPF960)

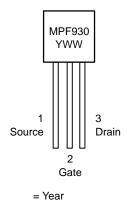
RDS(on) = 1.2 Ω (MPF990)

N-Channel





MARKING DIAGRAM & PIN ASSIGNMENT



WW = Work Week ORDERING INFORMATION

See detailed ordering and shipping information in the package dimensions section on page 3 of this data sheet.

Preferred devices are recommended choices for future use and best overall value.

ELECTRICAL CHARACTERISTICS (T_A = 25°C unless otherwise noted)

Characteristic		Symbol	Min	Тур	Max	Unit
OFF CHARACTERISTICS		'		-		
Drain–Source Breakdown Voltage (V _{GS} = 0, I _D = 10 μAdc)	MPF930 MPF960 MPF990	V(BR)DSX	35 60 90	- - -	- - -	Vdc
Gate Reverse Current (V _{GS} = 15 Vdc, V _{DS} = 0)		IGSS	-	-	50	nAdc
ON CHARACTERISTICS (Note 2.)						
Zero-Gate-Voltage Drain Current (VDS = Maximum Rating, VGS = 0)		IDSS	_	-	10	μAdc
Gate Threshold Voltage (I _D = 1.0 mAdc, V _{DS} = V _{GS})		VGS(Th)	1.0	-	3.5	Vdc
Drain-Source On-Voltage (VGS = 10 Vdc) (ID = 0.5 Adc) (ID = 1.0 Adc)	MPF930 MPF960 MPF990 MPF930 MPF960 MPF990	VDS(on)	- - - - -	0.4 0.6 0.6 0.9 1.2 1.2	0.7 0.8 1.2 1.4 1.7 2.4	Vdc
$(I_D = 2.0 \text{ Adc})$	MPF930 MPF960 MPF990		_ _ _	2.2 2.8 2.8	3.0 3.5 4.8	
Static Drain–Source On Resistance (V _{GS} = 10 Vdc, I _D = 1.0 Adc)	MPF930 MPF960 MPF990	rDS(on)	- - -	0.9 1.2 1.2	1.4 1.7 2.0	Ω
On–State Drain Current (VDS = 25 Vdc, VGS = 10 Vdc)		l _D (on)	1.0	2.0	-	Amps
SMALL-SIGNAL CHARACTERISTICS		<u> </u>				•
Input Capacitance (V _{DS} = 25 Vdc, V _{GS} = 0, f = 1.0 MHz)		C _{iss}	_	70	_	pF
Reverse Transfer Capacitance (V _{DS} = 25 Vdc, V _{GS} = 0, f = 1.0 MHz)		C _{rss}	-	20	_	pF
Output Capacitance (V _{DS} = 25 Vdc, V _{GS} = 0, f = 1.0 MHz)		C _{oss}	_	49	_	pF
Forward Transconductance (V _{DS} = 25 Vdc, I _D = 0.5 Adc)		9fs	200	380	-	mmhos
SWITCHING CHARACTERISTICS		, .		ı	I	I
Turn-On Time		ton	-	7.0	15	ns
Turn-Off Time		t _{off}	-	7.0	15	ns

^{2.} Pulse Test: Pulse Width $\leq 300 \,\mu\text{s}$, Duty Cycle $\leq 2.0\%$.

RESISTIVE SWITCHING

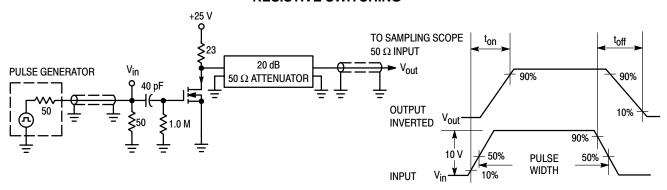
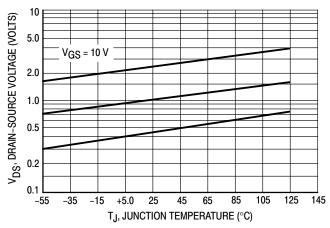


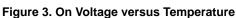
Figure 1. Switching Test Circuit

Figure 2. Switching Waveforms

ORDERING INFORMATION

Device	Package	Shipping
MPF930	TO-92	1000 Unit/Box
MPF930RLRE	TO-92	2000 Tape & Reel
MPF930A	TO-92	1000 Unit/Box
MPF930ARLRE	TO-92	2000 Tape & Reel
MPF960	TO-92	1000 Unit/Box
MPF960RLRA	TO-92	2000 Tape & Reel
MPF990	TO-92	1000 Unit/Box
MPF990RLRA	TO-92	2000 Tape & Reel
MPF990RLRP	TO-92	2000 Ammo Pack





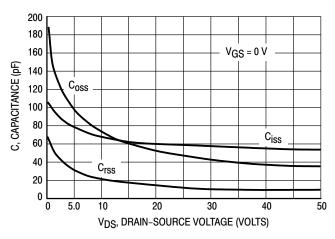


Figure 4. Capacitance Variation

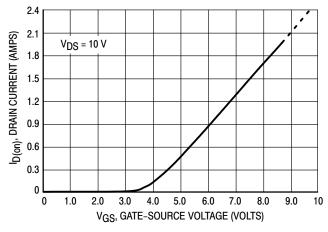


Figure 5. Transfer Characteristic

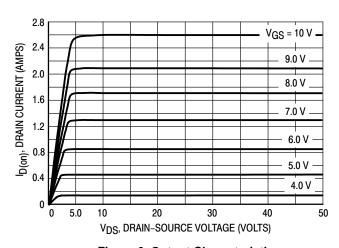


Figure 6. Output Characteristic

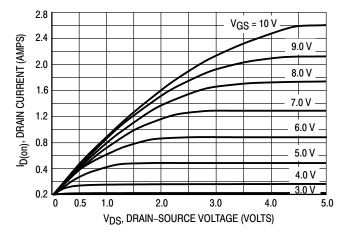
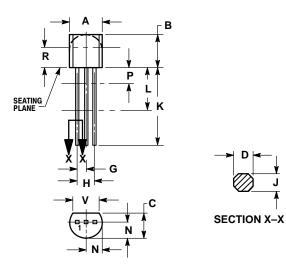


Figure 7. Saturation Characteristic

PACKAGE DIMENSIONS

TO-92 CASE 29-11 ISSUE AL



- NOTES:
 1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
 2. CONTROLLING DIMENSION: INCH.
 3. CONTOUR OF PACKAGE BEYOND DIMENSION R IS UNCONTROLLED.
 4. LEAD DIMENSION IS UNCONTROLLED IN P AND BEYOND DIMENSION K MINIMUM.

	INCHES		MILLIMETERS		
DIM	MIN	MAX	MIN	MAX	
Α	0.175	0.205	4.45	5.20	
В	0.170	0.210	4.32	5.33	
С	0.125	0.165	3.18	4.19	
D	0.016	0.021	0.407	0.533	
G	0.045	0.055	1.15	1.39	
Н	0.095	0.105	2.42	2.66	
J	0.015	0.020	0.39	0.50	
K	0.500		12.70		
L	0.250		6.35		
N	0.080	0.105	2.04	2.66	
P		0.100		2.54	
R	0.115		2.93		
V	0 135		3 43		

STYLE 22:
PIN 1. SOURCE
2. GATE
3. DRAIN





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